

# Average Current Mode Synchronous Controller With 5-Bit DAC

## FEATURES

- Combined DAC/Voltage Monitor and PWM with Synchronous Rectification Functions
- 5-Bit Digital-to-Analog (DAC) Converter
- 1% DAC/Reference Combined Accuracy
- Compatible with 5V and 12V Systems and 12V-only Systems
- Low Offset Current Sense Amplifier
- Programmable Oscillator Frequency Practical to 700kHz
- Foldback Current Limiting
- Overvoltage and Undervoltage Fault Windows
- 2Ω Totem Pole Outputs with Programmable Dead Times to Eliminate Cross-Conduction
- Chip Disable Function

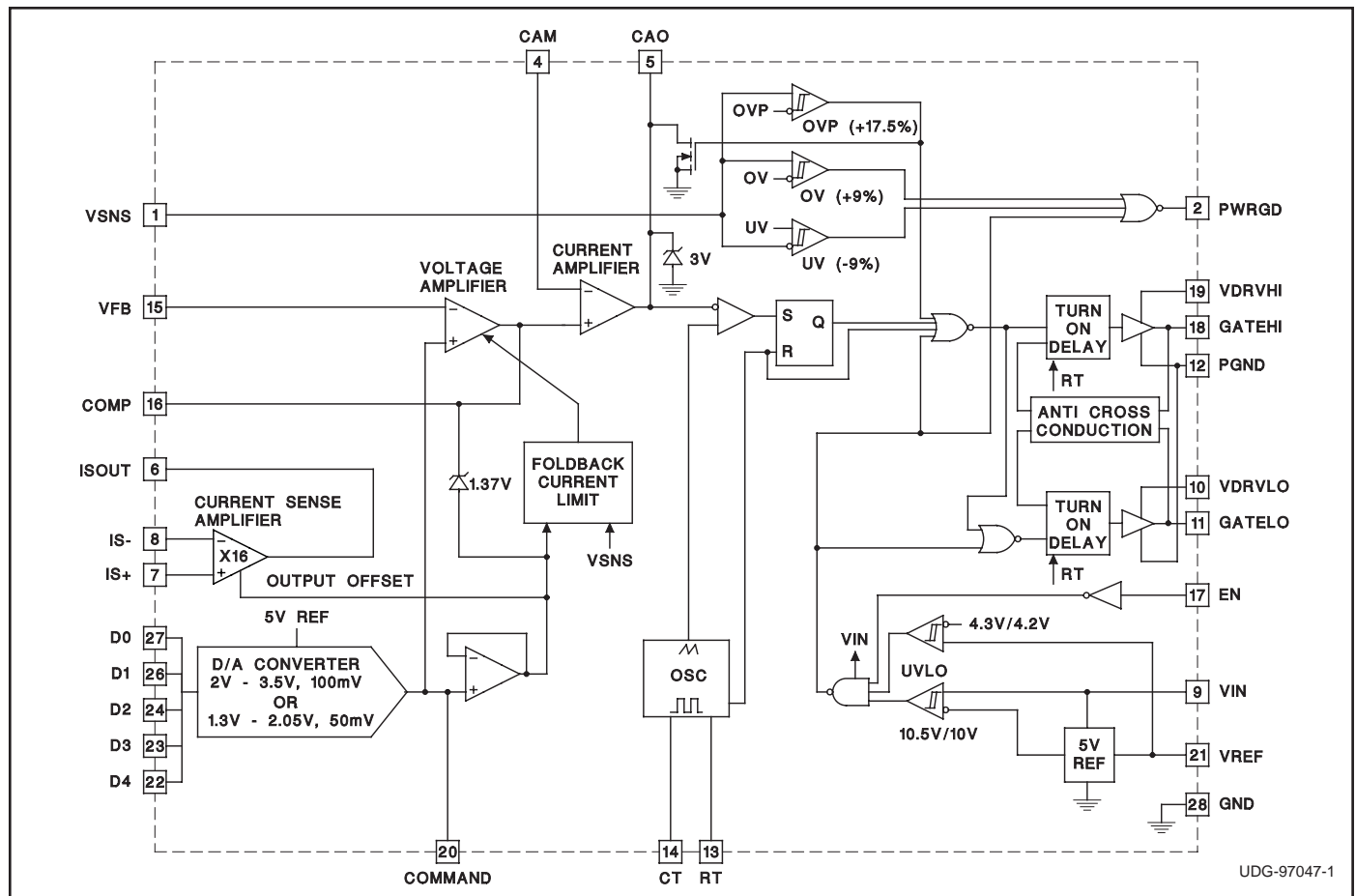
## DESCRIPTION

The UCC3882 combines high precision reference and voltage monitoring circuitry with average current mode PWM synchronous rectification controller circuitry to power high-end microprocessors with a minimum of external components. The UCC3882 converts 5V or 12V to an adjustable output ranging from 1.8VDC to 2.05VDC in 50mV steps and 2.1VDC to 3.5VDC in 100mV steps with 1% DC system accuracy.

The DAC output voltage is directly compatible with Intel's 5-bit VID code (Table 1) which covers 1.3V to 2.05V in 50mV steps and 2.1V to 3.5V in 100mV steps. The accuracy of the DAC/reference combination is better than 1%. Undervoltage lockout circuitry assures the correct logic states at the outputs during power up and power down. The overvoltage and undervoltage comparators monitor the system output voltage and indicate when it rises above or falls below its designed value by more than 9%. A second overvoltage comparator digitally forces GATEHI off and GATELO on when the system output voltage exceeds its designed value by more than 17.5%.

(continued)

## BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

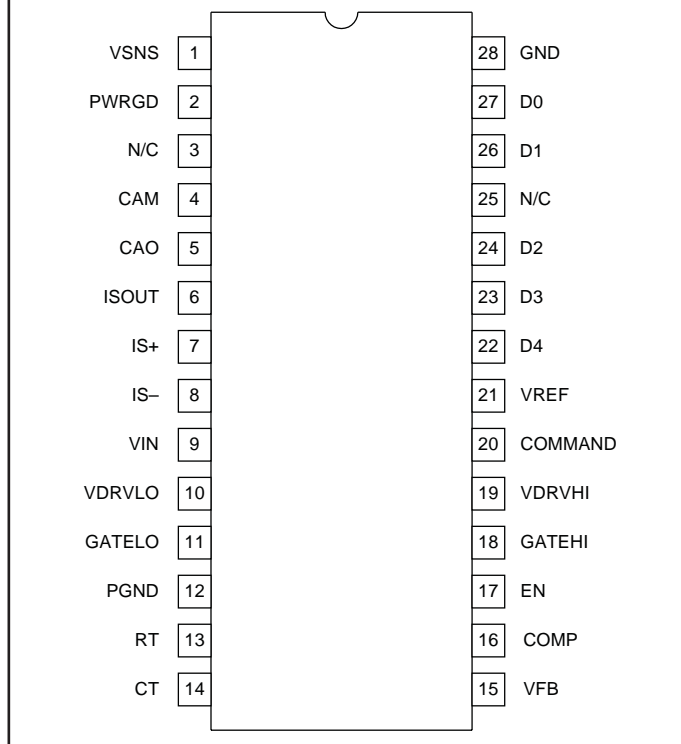
VDRVHI, GATEHI (Note 1)	−0.3V to 20V
VDRVLO, GATELO	−0.3V to 15V
All other pins referenced to GND	−0.3V to 5.3V
VIN	+15V
Storage Temperature	−65°C to +150°C
Junction Temperature	−55°C to +150°C
Lead Temperature (Soldering, 10 sec.)	+300°C

Currents are positive into, negative out of the specified terminal. Consult Packaging Section of Databook for thermal limitations and considerations of packages.

Note 1: 20V at no load. Derate to 18.5V when used with capacitive loads of greater than 1000pF in series with less than 20  $\Omega$ .

## CONNECTION DIAGRAM

DIL-28, SOIC-28 (Top View)  
N, DW or PW Packages



## DESCRIPTION (continued)

For all of the parts, grounding the EN pin disables the GATEHI and GATELO outputs, shutting down the power supply. For the 2882 and 3882 only, programming a DAC output voltage below 1.8V, or programming all of the VID pins high also disables the GATEHI and GATELO outputs. For the “−1” option parts, the GATEHI and GATELO outputs are switching, and the power supply output voltage regulates at the programmed DAC output voltage for all VID codes.

The voltage and current amplifiers have 2.5MHz gain-bandwidth product to satisfy high performance system requirements. The internal current sense amplifier permits the use of a low value current sense resistor, minimizing power loss. The oscillator frequency is exter-

nally programmed with RT and CT. The foldback circuit reduces the converter short circuit current limit to 50% of its nominal value when the converter is short-circuited, minimizing component stress and dissipation during abnormal conditions. The gate drivers are low impedance totem pole output stages capable of driving large external MOSFETs. Cross conduction is eliminated internally by programming the dead time between turn-off and turn on of the external high side and synchronous MOSFETs.

This device is available in a 28-pin wide body surface mount package. The UCC2882 is specified for operation from −25°C to +85°C and the UCC3882 is specified for operation from 0°C to 70°C.

**ELECTRICAL CHARACTERISTICS:** Unless otherwise specified, VIN = VDRVHI = VDRVLO = 12V, VSNS = 3.5V, VD0 = VD1 = VD2 = VD3 = VD4 = 0V, RT = 13k, CT = 1.8nF, EN = Open, 0°C < TA < 70°C, TA = TJ.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Undervoltage Lockout</b>					
VIN UVLO Turn-on Threshold			10.5	10.8	V
VIN UVLO Turn-off Threshold		9.5	10		V
UVLO Threshold Hysteresis		300	500	700	mV
<b>Supply Current</b>					
IIN	EN = 0V		7	12	mA

**ELECTRICAL CHARACTERISTICS:** Unless otherwise specified,  $V_{IN} = V_{DRVHI} = V_{DRVLO} = 12V$ ,  $V_{SNS} = 3.5V$ ,  $V_{D0} = V_{D1} = V_{D2} = V_{D3} = V_{D4} = 0V$ ,  $R_T = 13k$ ,  $C_T = 1.8nF$ ,  $EN = \text{Open}$ ,  $0^\circ C < T_A < 70^\circ C$ ,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>DAC/Reference</b>					
COMMAND Voltage Accuracy	$10.8V < V_{IN} < 13.2V$ , $I_{REF} = 0mA$ (Note 1)	-1		1	%
D0-D4 Voltage High	DX Pin Floating		5	5.2	V
D0-D4 Input Bias Current	DX Pin Tied to GND	-120	-70	-20	$\mu A$
<b>OVP Comparator</b>					
Trip Point	% Over COMMAND Voltage (Note 2)	10	17	25	%
Hysteresis			20		mV
<b>OV Comparator</b>					
Trip Point	% Over COMMAND Voltage (Note 2)	5	9	12	%
Hysteresis			20		mV
PWRGD On Resistance				470	$\Omega$
<b>UV Comparator</b>					
Trip Point	% Over COMMAND Voltage (Note 2)	-12	-9	-5	%
Hysteresis			20		mV
<b>Enable Pin</b>					
Pull Up Current	$V_{EN} = 2.5V$	-80	-50	-20	$\mu A$
<b>Voltage Error Amplifier</b>					
Input Offset Voltage	$V_{CM} = 3V$	-10	0	10	mV
Input Bias Current	$V_{CM} = 3V$	-0.5		0.5	$\mu A$
Open Loop Gain	$2.05V < V_{COMP} < 3.05V$		90		dB
Power Supply Rejection Ratio	$10.8V < V_{IN} < 15V$		85		dB
Output Sourcing Current	$V_{VFB} = 2V$ , $V_{COMMAND} = V_{COMP} = 2.5V$		-1.6	-0.8	mA
Output Sinking Current	$V_{VFB} = 3V$ , $V_{COMMAND} = V_{COMP} = 2.5V$		1		mA
<b>Current Sense Amplifier</b>					
Gain		15	16	17	V/V
Common Mode Rejection Ratio	$0V < V_{CM} < 4.5V$		60		dB
Power Supply Rejection Ratio	$10.8V < V_{IN} < 15V$		80		dB
Output Sourcing Current	$V_{IS-} = 2V$ , $V_{ISOUT} = V_{IS+} = 2.5V$		-4	-3	mA
Output Sinking Current	$V_{IS-} = 3V$ , $V_{ISOUT} = V_{IS+} = 2.5V$	3	4		mA
<b>Current Amplifier</b>					
Input Offset Voltage	$V_{CM} = 3V$		1		mV
Input Bias Current	$V_{CM} = 3V$		-0.1		$\mu A$
Open Loop Gain	$1V < V_{CAO} < 2.5V$		90		dB
Output Voltage High			3		V
Power Supply Rejection Ratio	$10.8V < V_{IN} < 15V$		80		dB
Output Sourcing Current	$V_{CAM} = 2V$ , $V_{CAO} = V_{COMP} = 2.5V$		-7		mA
Output Sinking Current	$V_{CAM} = 3V$ , $V_{CAO} = V_{COMP} = 2.5V$		17		mA
<b>Oscillator</b>					
Initial Accuracy	$T_A = 25^\circ C$	324	360	396	kHz
	$0^\circ C < T_A < 70^\circ C$	300	360	420	kHz
Valley to Peak Voltage			1.67		V
Frequency Change With Voltage	$10.8V < V_{IN} < 15V$		1		%
<b>Output Section (GATEHI and GATELO)</b>					
Output Low Voltage	$I_{GATE} = -100mA$		0.2		V
Output High Voltage	$I_{GATE} = 100mA$		11.8		V
Rise Time	$C_{GATE} = 3.3nF$ , $R_{SERIES} = 10\Omega$		20	80	ns
Fall Time	$C_{GATE} = 3.3nF$ , $R_{SERIES} = 10\Omega$		15	80	ns

**ELECTRICAL CHARACTERISTICS:** Unless otherwise specified,  $V_{IN} = V_{DRVHI} = V_{DRVLO} = 12V$ ,  $V_{SNS} = 3.5V$ ,  $V_{D0} = V_{D1} = V_{D2} = V_{D3} = V_{D4} = 0V$ ,  $R_T = 13k$ ,  $C_T = 1.8nF$ ,  $EN = \text{Open}$ ,  $0^\circ C < T_A < 70^\circ C$ ,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Turn On Delay</b>					
GATEHI Turn Off to GATELO Turn On			150		ns
GATELO Turn Off to GATEHI Turn On			135		ns
<b>Foldback Current Limit</b>					
Clamp Level	$V_{COMMAND} = V_{SNS}$ $V_{FB} = V_{COMMAND} - 100mV$ (Note 3)		1.37		V
	$V_{SNS} = 0$ $V_{FB} = V_{COMMAND} - 100mV$ (Note 3)		0.71		V
System Short Circuit Current Limit	$V_{COMMAND} = 2.3V$ $V_{FB} = 0V$ (Note 4)	14.4	17	22	A

Note 1: This test measures the combined errors of the COMMAND voltage and the voltage amplifier offset voltage. Applies to all DAC codes from 1.8V to 3.5V.

Note 2: This percentage is measured with respect to the ideal COMMAND voltage programmed by the D0 - D4 pins.

Note 3: This voltage is measured with respect to the COMMAND voltage.

Note 4: The calculation of this parameter assumes an offchip sense resistor value of  $0.005\Omega$ . This test encompasses all sources of error from the IC.

## PIN DESCRIPTIONS

**CAM:** This pin is the inverting input to the current amplifier. The average load current feedback from the ISOUT pin is applied through a resistor to this pin. The current loop compensation network is also connected to this pin (see CAO below).

**CAO:** This pin is the current amplifier output. The current loop compensation network is connected between this pin and the CAM pin. The voltage on this pin is the input to the PWM comparator and regulates the output voltage of the system. The voltage at this output ranges from below 0.5V (forcing 0% duty cycle) to above 2.5V forcing maximum duty cycle. A 3V clamp circuit prevents the CAO voltage from rising excessively past the oscillator peak voltage, for excellent transient response.

**COMP:** This pin is the voltage error amplifier output voltage. The system voltage compensation network is applied between COMP and VFB. A 1.37V clamp above COMMAND is used to force the power supply into current limit mode when the output is short circuited. See the Applications Section for programming current limit.

**COMMAND:** This pin is the output of the 5-bit digital-to-analog (DAC) converter and is the non-inverting input of the voltage error amplifier. The voltage on this pin sets the switching regulator output voltage. The COMMAND voltage is set by the DAC input pins D0-D4, according to Table 1. The COMMAND source impedance is typically  $1.2k\Omega$  and must therefore drive only high impedance inputs if accuracy is to be maintained. Bypass COMMAND with a  $0.01\mu F$ , low ESR, low ESL capacitor for best circuit noise immunity.

**CT:** This pin is used with  $R_T$  to program the internal PWM oscillator frequency. Use a high quality capacitor for best oscillator accuracy. See the Applications Section for programming the oscillator.

**D0-D4:** These are the digital input control codes for the DAC (See Table 1). The DAC is comprised of two ranges set by D4 and with D0 representing the least significant bit (LSB) and D3, the most significant bit (MSB). A bit is set low by being connected to GND; a bit is set high by floating it, or connecting it to a 5V source. Each control pin is pulled up to approximately 5V by an internal pull up.

**EN:** This input is used to disable the GATEHI and GATELO outputs, resulting in disabling the power supply. Pulling EN to GND causes the GATEHI and GATELO outputs to be held low, while floating the pin or pulling it up to 5V ensures normal operation. EN is pulled up to 5V internally.

**GATEHI:** This output provides a low impedance totem pole driver to drive the high-side external MOSFET. A series resistor between this pin and the gate of the external MOSFET is recommended to prevent gate drive ringing and overshoot. Good layout techniques should be used to prevent GATEHI from ringing more than 0.3V below PGND. The VDRVHI pin provides the power for the GATEHI pin. GATEHI is disabled during UVLO and overvoltage conditions. For the 2882/3882 only, GATEHI is also disabled when the COMMAND voltage is programmed between 1.3 and 1.75V, or where the D0-D4 pins are all logic high levels, indicating no processor present.

## PIN DESCRIPTIONS (continued)

**GATELO:** This output provides a low impedance totem pole driver to drive the low-side synchronous external MOSFET. A series resistor between this pin and the gate of the external MOSFET is recommended to prevent gate drive ringing and overshoot. Good layout techniques should be used to prevent GATELO from ringing more than 0.3V below PGND. The VDRVLO pin provides the power for GATELO. GATELO is disabled during UVLO conditions. For the 2882/3882 only, GATELO is also disabled when the COMMAND voltage is programmed between 1.3 and 1.75V, or where the D0-D4 pins are all logic high levels, indicating no processor present.

**GND:** Ground reference for the device. All voltages, with the exception of the GATE voltages, are measured with respect to GND. Bypass capacitors on VIN, VREF, VSNS and COMMAND should be connected directly to the ground plane near GND.

**IS-:** This pin is the inverting input to the current sense amplifier and is connected to the low side of the average current sense resistor.

**IS+:** This pin is the non-inverting input to the current sense amplifier and is connected to the high side of the average current sense resistor.

**ISOUT:** This pin is the output of the current sense amplifier. The voltage on this pin is equal to the voltage across the sense resistor multiplied by 16 and biased up by the COMMAND voltage. This voltage is used for Average Current mode control and for current limiting.

**PGND:** This pin provides a dedicated ground for the output gate drivers. The GND and PGND pins should be connected externally using a short PC board trace or plane. Decouple VDRVHI and VDRVLO to PGND with low ESR capacitor of at least 0.1 $\mu$ F.

**PWRGD:** This pin is an open drain output which is driven low to reset the microprocessor when VSNS rises above or falls below its nominal value by 9%. The on resistance of the open-drain switch will be no higher than 470 $\Omega$ . This output should be pulled up to a logic level voltage and should be programmed to sink 1mA or less.

**RT:** This pin is used with CT to program the internal PWM oscillator frequency. It is also used to program the delay times between the external MOSFET turn on and turn off periods, which eliminates cross conduction in those MOSFETs. See the Applications Section for programming the oscillator and for controlling cross conduction.

**VDRVHI:** This pin supplies power to the high side output driver, GATEHI. Connect VDRVHI to an 18V or lower source for power supplies converting 12VDC to lower voltages, and to a 12V source for systems for power supplies converting 5VDC. This pin should be bypassed directly to PGND using a low ESR capacitor.

**VDRVLO:** This pin supplies power to the low side output driver, GATELO. VDRVLO is typically connected to a 12V source, but may be connected to a 5V source for driving logic level MOSFETs. This pin should be bypassed directly to PGND using a low ESR capacitor.

**VIN:** This pin supplies power to the chip. Connect VIN to a stable voltage source that is at least 10.8V above GND. The GATEHI, GATELO and PWRGD outputs will be held low until VCC exceeds the upper undervoltage lockout threshold. This pin should be bypassed directly to GND.

**VFB:** This pin is the inverting input to the error amplifier. This input is connected to COMP through a feedback network and to the power supply output through a resistor or a divider network.

**VREF:** This pin provides an accurate 5V reference and is internally short circuit current limited. VREF powers the D/A Converter and also provides a threshold voltage for the UVLO comparator. For best reference stability, bypass VREF directly to GND with a low ESR, low ESL capacitor of at least 0.01 $\mu$ F.

**VSNS:** This pin is connected to the system output voltage through a low pass R-C filter. When the voltage on VSNS rises above or falls below the COMMAND voltage by 9%, the PWRGD output is driven low to reset the microprocessor. When the voltage on VSNS rises above the COMMAND voltage by 17.5%, the OVP comparator disables the GATEHI output and enables the GATELO output, forcing 0% duty cycle on the power supply. This pin is also used by the foldback current limiting circuitry to indicate when the output voltage has been short circuited. VSNS should be decoupled very closely to the IC with a capacitor to GND. The OV and UV comparators' hysteresis is typically 20mV, requiring good layout and filtering techniques to insure that noise and ground-bounce do not inadvertently trip the OV and UV comparators. It is recommended that an R-C filter set to approximately  $F_s/10$  be used to filter noise from the system output, where  $F_s$  is the oscillator frequency.



## DAC INFORMATION

The 5-bit Digital-to-Analog Converter (DAC) is programmed according to Table 1. The COMMAND voltage is always active as long as the UCC3882 VIN pin is above the undervoltage lockout voltage. For the 2882/3882 only, the output gate drives GATEHI and

GATELO are disabled at certain DAC codes, as shown in Table 1. Disabling the gate drives disables the power supply. For the 2882 -1 and 3882 -1, the GATEHI and GATELO drives are enabled for all DAC codes. For a given code, the power supply output regulates at the corresponding COMMAND voltage.

Digital Command					Command Voltage	GATEHI/GATELO Status	Digital Command					Command Voltage	GATEHI/GATELO Status
D4	D3	D2	D1	D0			D4	D3	D2	D1	D0		
0	1	1	1	1	1.300	Note 1	1	1	1	1	1	2.000	Note 1
0	1	1	1	0	1.350	Note 1	1	1	1	1	0	2.100	Enabled
0	1	1	0	1	1.400	Note 1	1	1	1	0	1	2.200	Enabled
0	1	1	0	0	1.450	Note 1	1	1	1	0	0	2.300	Enabled
0	1	0	1	1	1.500	Note 1	1	1	0	1	1	2.400	Enabled
0	1	0	1	0	1.550	Note 1	1	1	0	1	0	2.500	Enabled
0	1	0	0	1	1.600	Note 1	1	1	0	0	1	2.600	Enabled
0	1	0	0	0	1.650	Note 1	1	1	0	0	0	2.700	Enabled
0	0	1	1	1	1.700	Note 1	1	0	1	1	1	2.800	Enabled
0	0	1	1	0	1.750	Note 1	1	0	1	1	0	2.900	Enabled
0	0	1	0	1	1.800	Enabled	1	0	1	0	1	3.000	Enabled
0	0	1	0	0	1.850	Enabled	1	0	1	0	0	3.100	Enabled
0	0	0	1	1	1.900	Enabled	1	0	0	1	1	3.200	Enabled
0	0	0	1	0	1.950	Enabled	1	0	0	1	0	3.300	Enabled
0	0	0	0	1	2.000	Enabled	1	0	0	0	1	3.400	Enabled
0	0	0	0	0	2.050	Enabled	1	0	0	0	0	3.500	Enabled

**Table 1. Programming the Command Voltage for the UCC3882**

## APPLICATION INFORMATION

This IC is intended to be used in a high performance power supply to power the Pentium® II or a similar processor. Figure 1 shows a typical power supply application circuit which converts +5V to lower voltages required by the Pentium® II Processor.

### Synchronous Switching Delay Time

Figure 2 shows that the fundamental difference between a Buck and a Synchronous Buck regulator is the use of a MOSFET rather than a Schottky diode as the low side or free-wheeling switch.

In order to maintain safe and efficient operation of a Synchronous Buck regulator, both MOSFETs, Q1 and Q2, should never be turned on at the same time. Having both MOSFETs on at the same time results in cross conduction, which can result in excessively high power dissipation in one or both MOSFETs. The UCC3882 has a built in delay between the turn OFF of one MOSFET and the turn ON of the other MOSFET. This delay is a controlled delay between the GATEHI and GATELO drive outputs and is programmable by the selection of the resistor RT. Controlling the delay between the gate drive outputs is

only part of the solution. The power supply designer must also understand intrinsic delays involving MOSFET turn on, turn off, rise and fall times in order to insure that there is no cross conduction.

It is recommended that a value between 10kΩ and 15kΩ be used for RT, which minimizes the delay and can result in the highest efficiency operation. A higher value of RT will result in a larger delay between the MOSFET Gate transitions. RT should be between 10kΩ minimum and 50kΩ maximum.

### Programming the Oscillator

The first step in programming the oscillator is choosing the value of RT as described above. The second step is to program the frequency according to the curves shown in Figure 3, by choosing the appropriate capacitor value.

For convenience, values are shown in Table 1 for nominal frequencies from 100kHz to 700kHz using standard resistors and capacitor values.

## APPLICATION INFORMATION (continued)

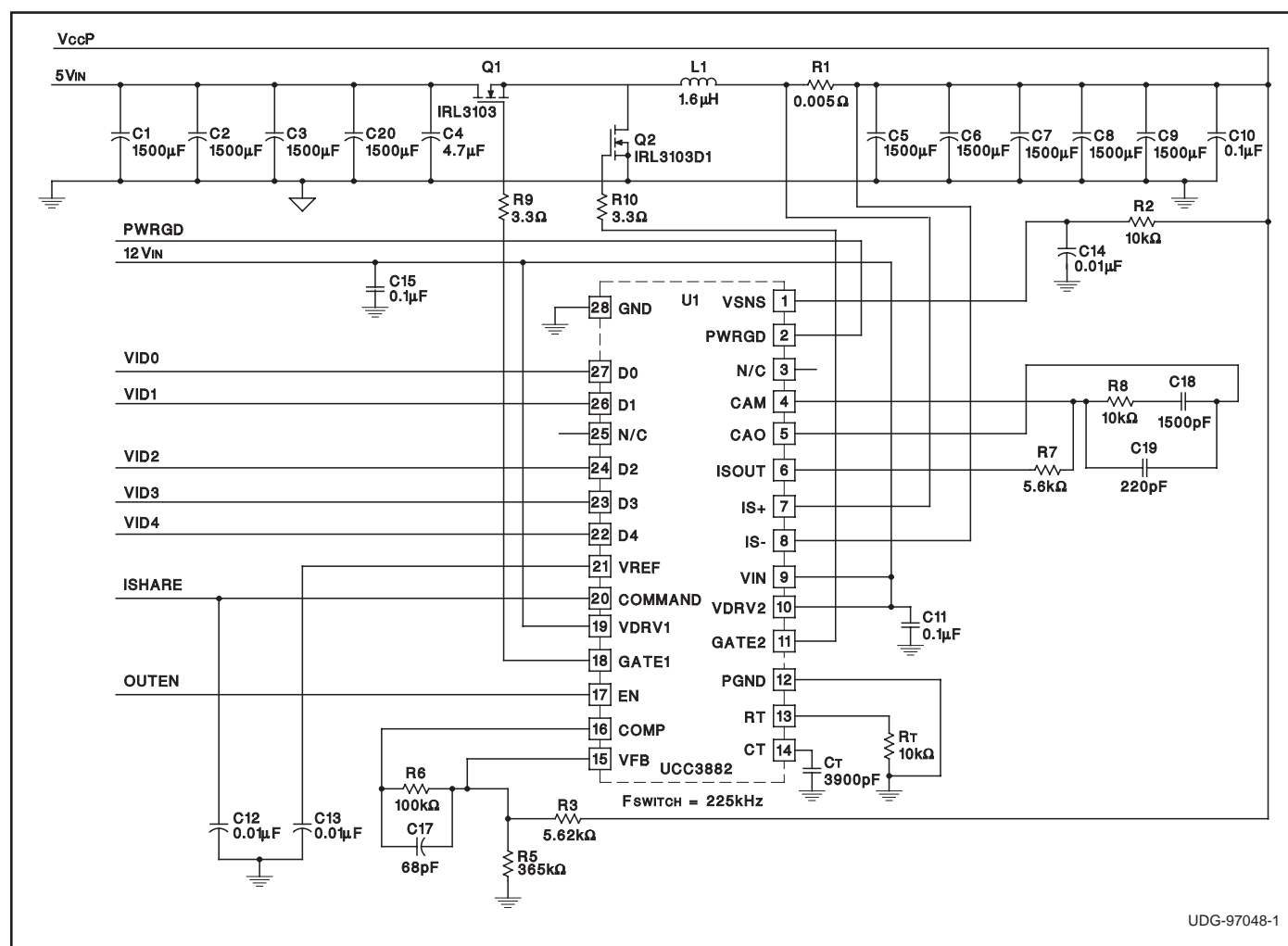
FREQUENCY	R <sub>T</sub>	C <sub>T</sub>
(kHz)	(kΩ)	(pF)
100	14.7	5600
200	11.0	3900
300	10.5	2700
400	11.3	1800
500	12.7	1200
600	10.7	1200
700	11.0	1000

**Table 2. Programming Standard Frequencies**

An excessively long delay time between gate drive signals, or a delay time that is too small, will result in an inefficient power supply design. The third step in programming the oscillator is to observe the actual circuit waveforms to insure that the delay is optimal. The designer should vary R<sub>T</sub> and C<sub>T</sub> accordingly to adjust the delay time and to program the proper oscillator frequency.

## Using an External Schottky Diode in Parallel With the Low Side MOSFET

The purpose of using a synchronous buck regulator is to substitute a low voltage drop MOSFET in place of a Schottky diode as the low side switch. An external Schottky diode may still be required however, in order to reduce the losses due to the reverse recovery of the low-side MOSFET body diode. Figure 4 illustrates the effects on power losses due to the non-ideal nature of a typical MOSFET body diode. I<sub>RM</sub> is the peak recovery current of the body diode of Q2 and I<sub>LOUT</sub> is the current of the output inductor. Using a parallel Schottky diode can reduce these losses and increase circuit efficiency. The size of the diode should be increased as a function of load current, input voltage, and operating frequency. The diode should be as close to the lower MOSFET, Q2, as possible, to reduce stray inductance.



**Figure 1. Application circuit - Pentium® II power supply.**

## APPLICATION INFORMATION

### Choosing R<sub>SENSE</sub> to Set the Current Limit

R<sub>SENSE</sub> is chosen to limit the maximum (short circuit) current of the power supply. The short circuit current equation for the UCC3882 is:

$$I_{SC} = \frac{1.37V}{R_{SENSE} \cdot 16}$$

and therefore, the value of the sense resistor, for a chosen short circuit current is:

$$R_{SENSE} = \frac{1.37V}{I_{SC} \cdot 16}$$

The short circuit current limit does vary slightly as a function of the switching regulator's output inductor value and operating frequency because a high value of ripple current will reduce the average short circuit current limit. Figure 5 shows the variation in I<sub>sc</sub> given common values for the UCC3882. The UCC3882 is nominally configured so that a 0.005mΩ resistor will set the current limit to approximately 17A.

The UCC3882 incorporates short circuit current foldback, as shown in Figure 6. When the output of the power supply is short circuited, the output voltage falls. When the output voltage reaches 1/2 of its nominal voltage (COMMAND/2) then the output current is reduced. This feature reduces the amount of current in the MOSFETs and capacitors, and insures high reliability.

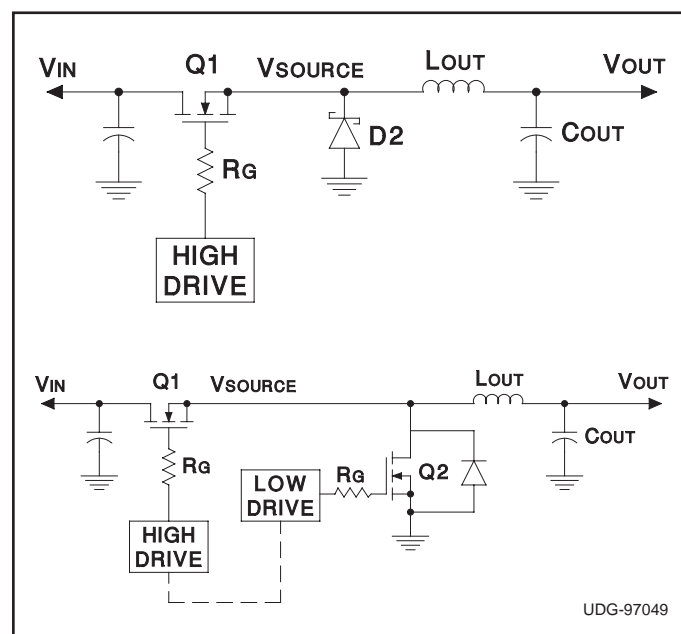


Figure 2. Buck vs. synchronous buck regulator.

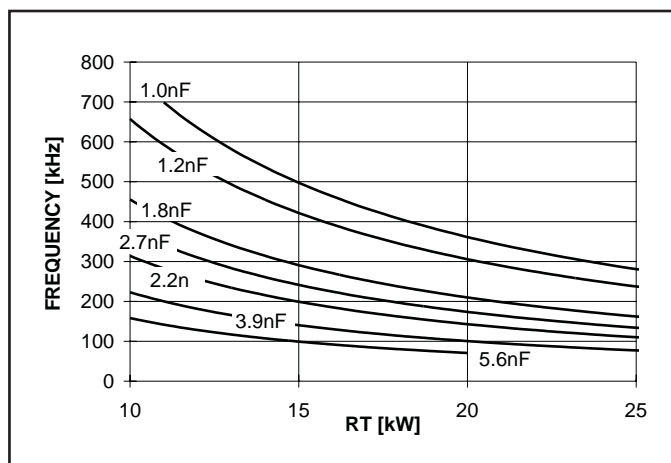


Figure 3. Programming UCC3882 oscillator frequency.

### Choosing V<sub>DRVLO</sub>, V<sub>DRVHI</sub> and V<sub>IN</sub>

The UCC3882 requires a nominal 12V input supplied at V<sub>IN</sub>. V<sub>DRVLO</sub> and V<sub>DRVHI</sub> can be set to any voltage less than 18.5V, and may be set individually. A power supply deriving its power from +5V should use +12V at the V<sub>DRVHI</sub> pin, but may use either +5V or +12V depending on the drive requirements of the synchronous low-side MOSFET. A power supply deriving its power from +12V should use +18V at V<sub>DRVHI</sub> in order to provide adequate voltage (6V) gate drive to the high-side MOSFET. V<sub>IN</sub> must be less than +15V.

### Input Capacitors

The input capacitors are chosen primarily based on their switching frequency RMS current handling capability and their voltage rating. The input capacitors must handle virtually all of the RMS current at the switching frequency, even if the circuit does not have an input inductor. The switching current in the input capacitors appears as shown in Figure 7.

Aluminum or tantalum capacitors can be used. The amount of RMS current in an Electrolytic capacitor has a strong impact on the reliability and lifetime of the capacitor. Other factors which affect the life of an input capacitor are internal heat rise, external airflow, the amount of time that the circuit operates at maximum current and the operating voltage. The curves in Figure 8 show the RMS current handled by the total input capacitance in typical VRM circuits powered from 5V or from 12V.



## APPLICATION INFORMATION (continued)

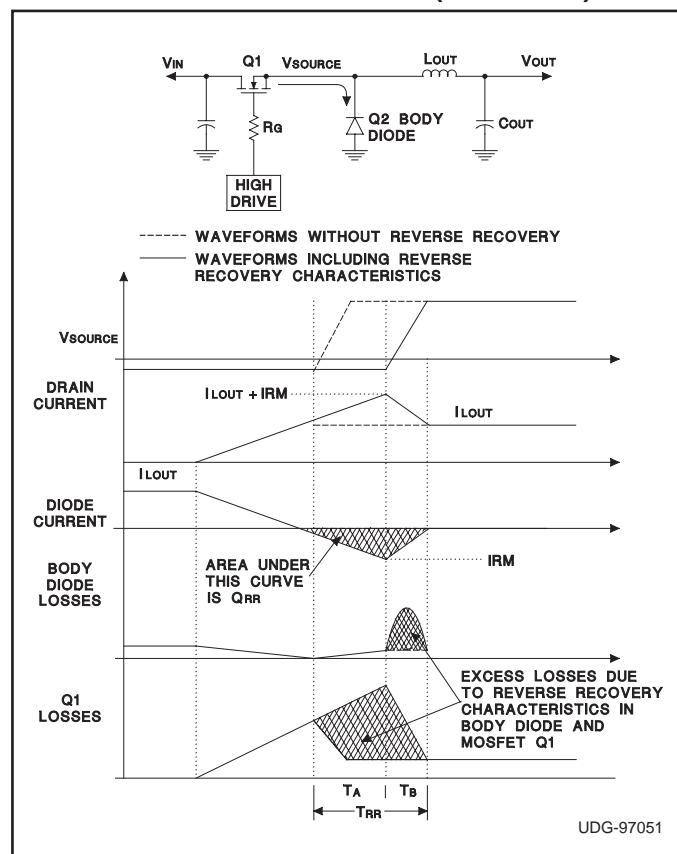


Figure 4. Effects of reverse recovery in a synchronous rectifier.

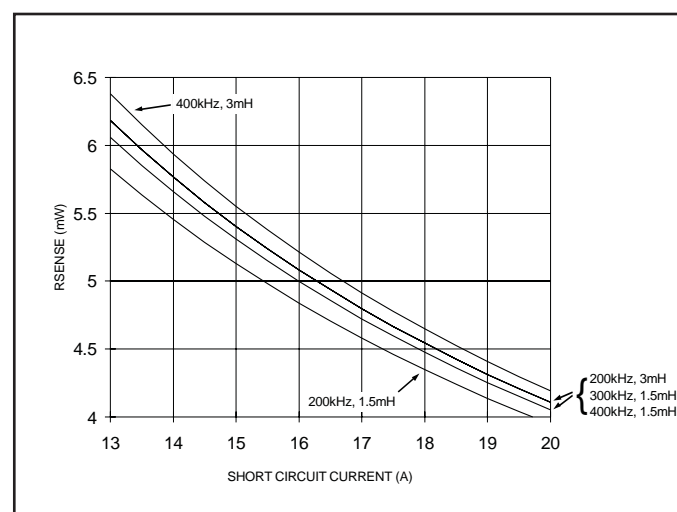


Figure 5. Short circuit current limit vs. RSENSE for various frequency and inductor values.

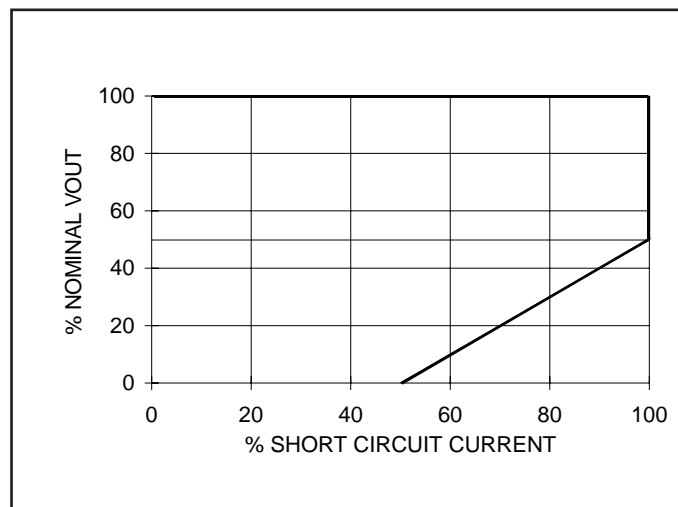


Figure 6. Short circuit foldback reduces stress on circuit components by reducing short circuit current.

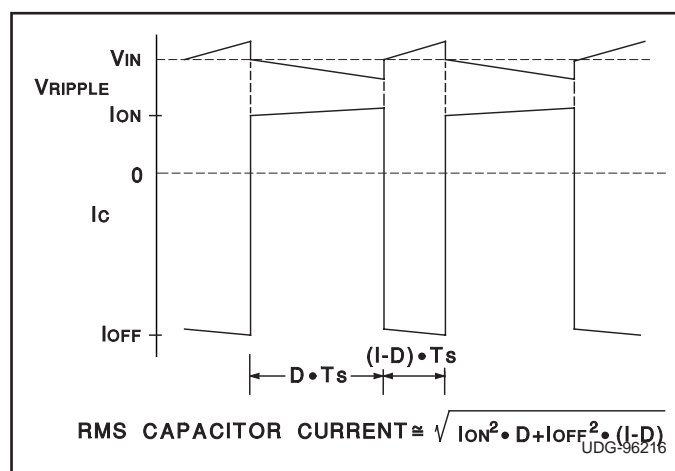


Figure 7. Input capacitors current waveform.

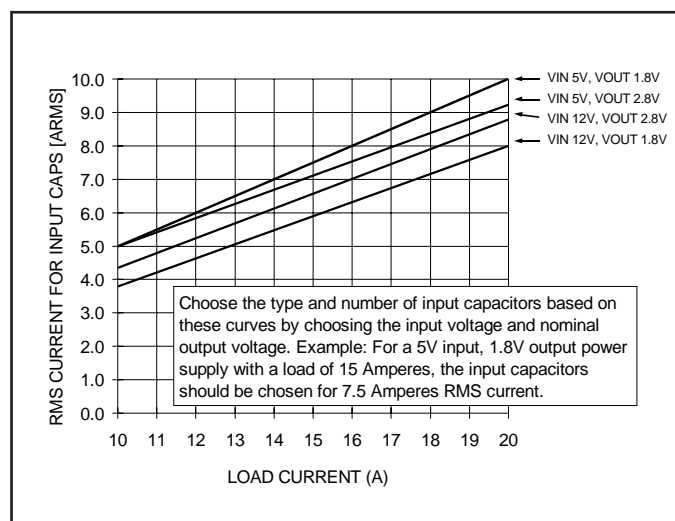


Figure 8. Load current vs RMS current for input capacitors - Pentium® II Family.

## APPLICATION INFORMATION (continued)

### Demonstration Kit Design and Performance

A demonstration circuit was built based on the UCC3882 and utilizing an Intel VRM 8.1 form factor connector. The schematic is shown in Figure 9 and the Bill of Materials in Table 3. The circuit is configured for the following operating parameters:

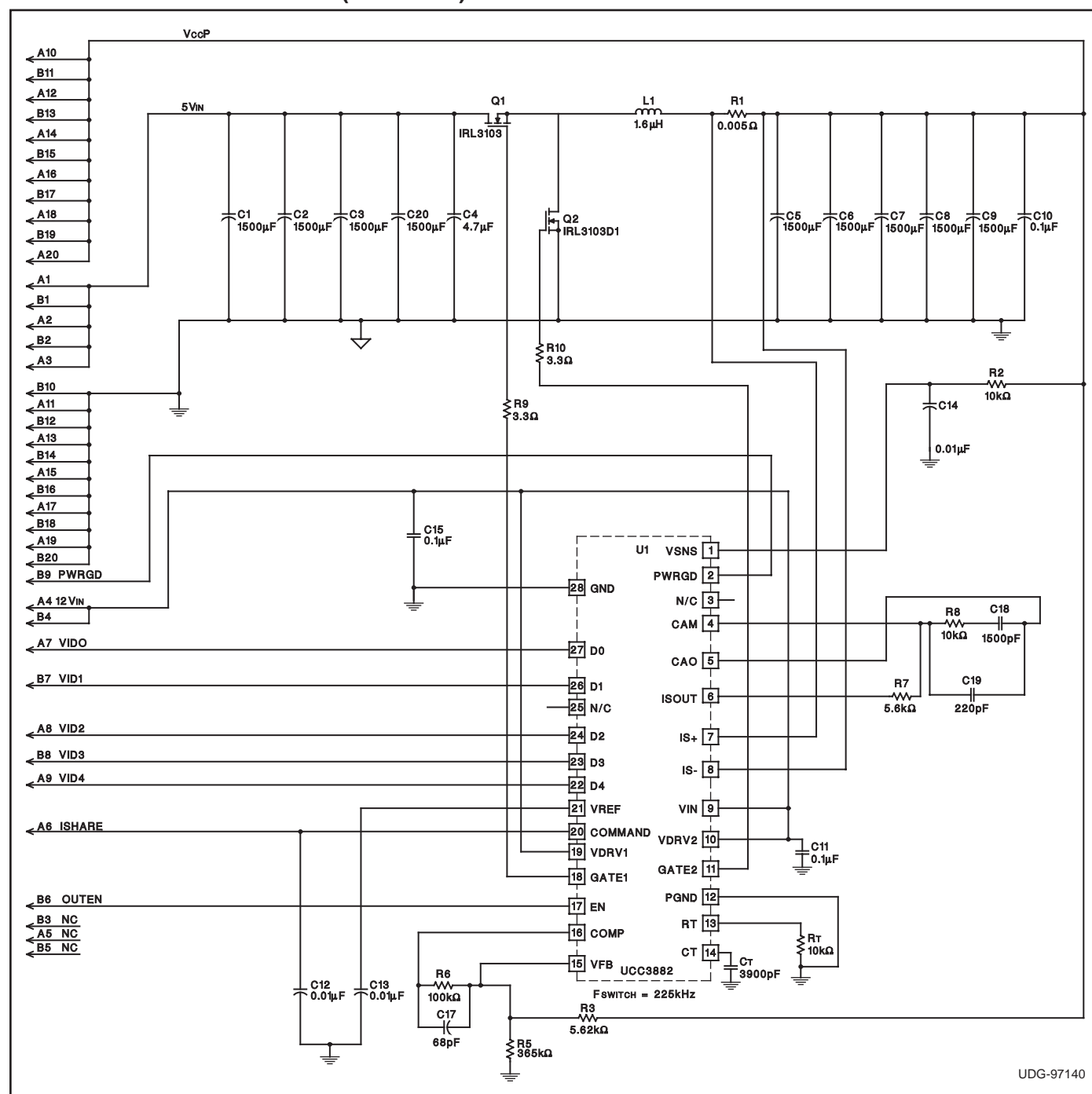
- Switching Frequency = 225kHz
- Rated Output Current = 15A

- Short Circuit Current = 17A Nominal
- Output Voltage: 1.8V to 2.8V Configured by VID Code
- Airflow: 100 LFM
- Temperature: 0 to 60°C
- Regulation: Per Intel VRM 8.1 DC-DC Converter Design Guidelines

Figures 12 - 14 show the performance of the circuit.

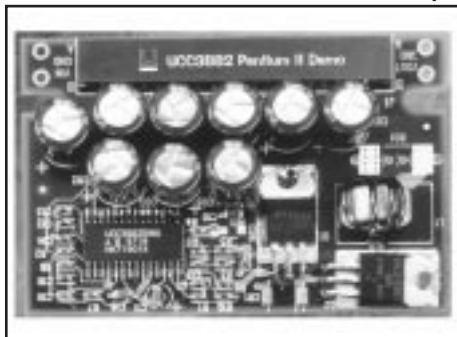
REF	DESCRIPTION	PACKAGE
U1	Unitrode UCC3882 DAC/PWM	SOIC-28 WIDE
C01	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C02	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C03	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C04	Sprague/Vishay 595D475X0016A2B, 4.7uF 16V Tantalum	SPRAGUE Size A
C05	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C06	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C07	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C08	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C09	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
C10	0.10μF Ceramic	1206 SMD
C11	0.10μF Ceramic	1206 SMD
C12	0.01μF Ceramic	0603 SMD
C13	0.01μF Ceramic	0603 SMD
C14	0.01μF Ceramic	0603 SMD
C15	0.10μF Ceramic	1206 SMD
C17	68pF NPO Ceramic	0603 SMD
C18	1000pF Ceramic	0603 SMD
C19	220pF NPO Ceramic	0603 SMD
C20	Sanyo 6MV1500GX, 1500μF, 6.3V, Aluminum Electrolytic	10x20mm Radial Can
CT	3900pF Ceramic	0603 SMD
J1	AMP 532956-7 40 Pin Connector	40 Pin
L1	Toroid T51-52C, 5 Turns #16AWG, 1.6μH	Toroid
Q1	International Rectifier IRL3103, 30V, 56A	TO-220AB, layed down
Q2	International Rectifier IRL3103D1, 30V, 56A	TO-220AB, layed down
R01	5mΩ, PCB Resistor	Copper Trace
R02	10kΩ, 5%, 1/16 Watt	0603 SMD
R03	5.62kΩ, 1%, 1/16 Watt	0603 SMD
R05	365kΩ, 1%, 1/16 Watt	0603 SMD
R06	100kΩ, 5%, 1/16 Watt	0603 SMD
R07	5.6kΩ, 5%, 1/16 Watt	0603 SMD
R08	10kΩ, 5%, 1/16 Watt	0603 SMD
R09	3.3Ω, 5%, 1/16 Watt	0603 SMD
R10	3.3Ω, 5%, 1/16 Watt	0603 SMD

**Table 3. Bill of materials.**

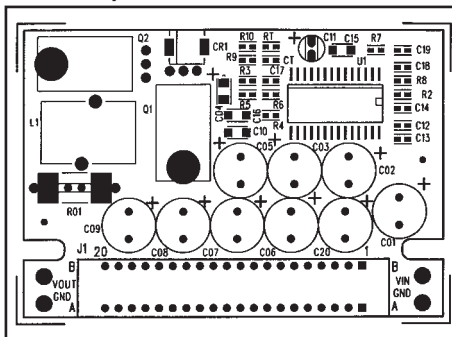
**APPLICATION INFORMATION (continued)**

**Figure 9. Reference design - UCC3882 5-bit synchronous rectifier PWM controller for the Intel Pentium®II processor.**

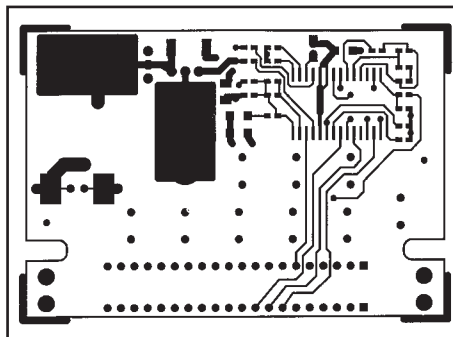
### APPLICATION INFORMATION (continued)



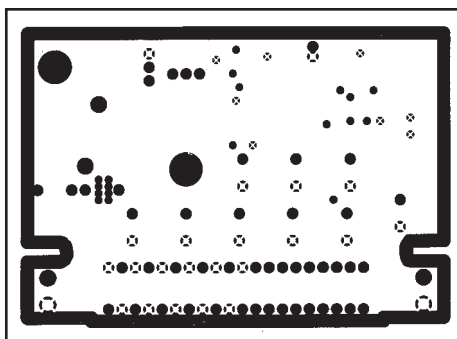
**Figure 10. Demo board.**



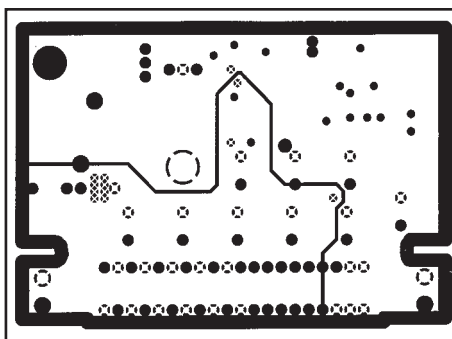
**Figure 11a. COMP silkscreen.**



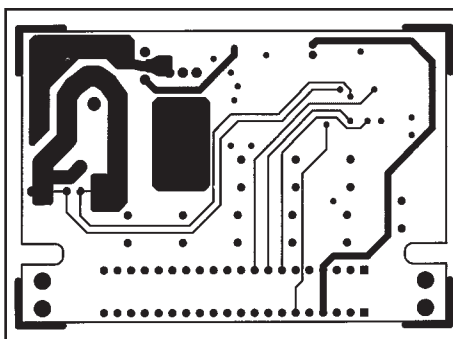
**Figure 11b. COMP side.**



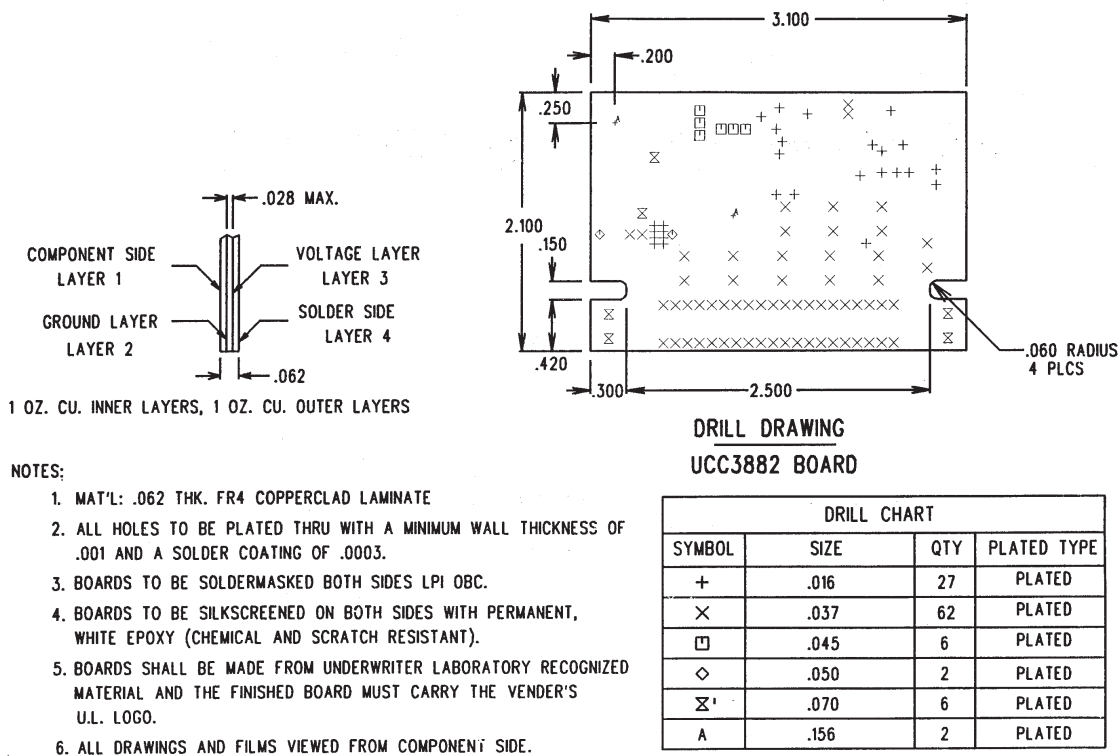
**Figure 11c. GND layer.**



**Figure 11d. PWR layer.**



**Figure 11e. Solder side.**



**Figure 11f. Drill drawing.**

APPLICATION INFORMATION (cont.)

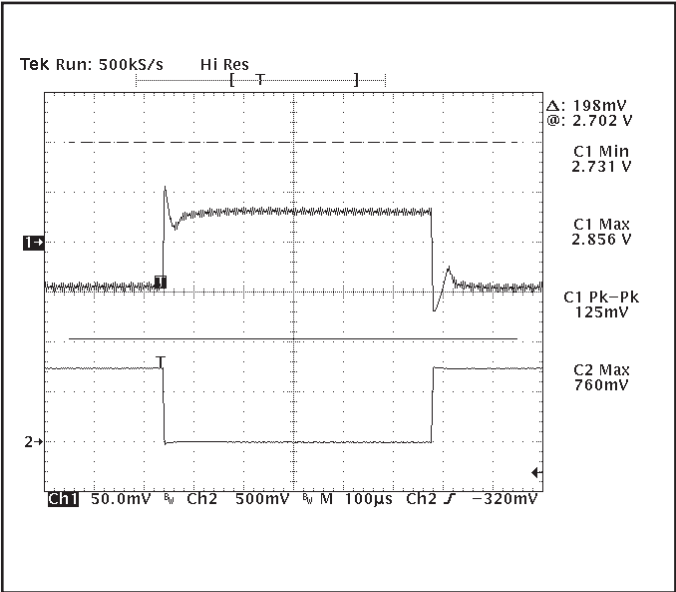


Figure 12. Transient response to 15.2A step load channel 2 scale is 50mV/A.

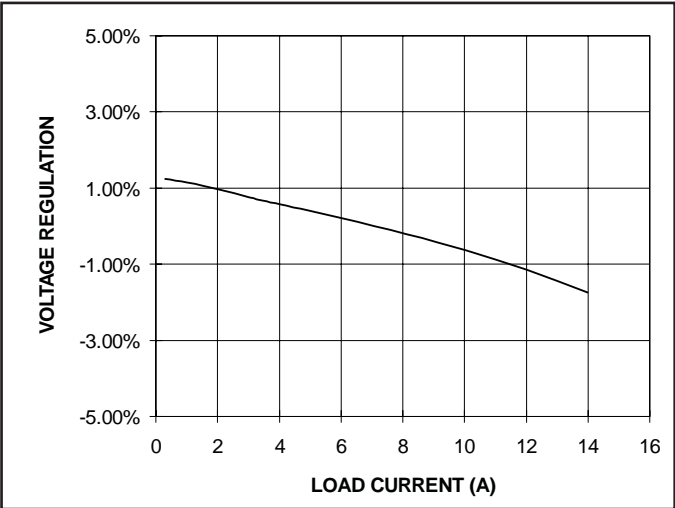


Figure 14. Load regulation.

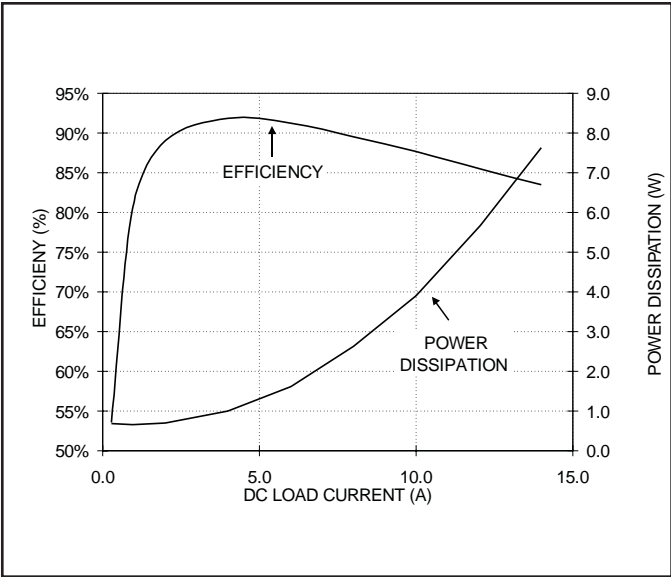


Figure 13. UCC3882 demo kit efficiency.



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